## NSN 5961-01-294-1292

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-1292 **Inclosure Material:** Plastic **Overall Length:** 0.082 inches **Terminal Length:** 0.064 inches **Overall Diameter:** 0.084 inches **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Matched pair; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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